

# CMOS Low Power Dual 2:1 Mux/Demux USB 2.0 (480 Mbps)/USB 1.1 (12 Mbps)

### **Data Sheet**

### FEATURES

USB 2.0 (480 Mbps) and USB 1.1 (12 Mbps) signal switching compliant Tiny 10-lead 1.3 mm × 1.6 mm mini LFCSP package and 12-lead 3 mm × 3 mm LFCSP package 2.7 V to 3.6 V single-supply operation Typical power consumption: <0.1 μW RoHS compliant

### **APPLICATIONS**

USB 2.0 signal switching circuits Cellular phones PDAs MP3 players Battery-powered systems Headphone switching Audio and video signal routing Communications systems

### **GENERAL DESCRIPTION**

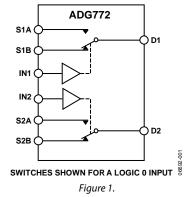
The ADG772 is a low voltage CMOS device that contains two independently selectable single-pole, double throw (SPDT) switches. It is designed as a general-purpose switch and can be used for routing both USB 1.1 and USB 2.0 signals.

This device offers a data rate of 1260 Mbps, making the device suitable for high frequency data switching. Each switch conducts equally well in both directions when on and has an input signal range that extends to the supplies. The ADG772 exhibits break-before-make switching action.

The ADG772 is available in a 12-lead LFCSP and a 10-lead mini LFCSP. These packages make the ADG772 the ideal solution for space-constrained applications.

## **ADG772**

### FUNCTIONAL BLOCK DIAGRAM



### **PRODUCT HIGHLIGHTS**

- 1. 1.6 mm × 1.3 mm mini LFCSP package.
- 2. USB 1.1 (12 Mbps) and USB 2.0 (480 Mbps) compliant.
- 3. Single 2.7 V to 3.6 V operation.
- 4. 1.8 V logic compatible.
- 5. RoHS compliant.

#### Document Feedback

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### **REVISION HISTORY**

5/16—Rev. B to Rev. C	
Changes to Figure 3	5
Updated Outline Dimensions	2
Changes to Ordering Guide	2

### 4/13—Rev. A to Rev. B

Added EPAD Notation	. 5
Changes to Figure 10	
Updated Outline Dimensions	
Changes to Ordering Guide	12

### 6/08—Rev. 0 to Rev. A

Changes to Product Highlights	1
Changes to Input High Voltage, $V_{\ensuremath{\text{INH}}}$ , Parameter	3

### 8/07—Revision 0: Initial Version

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## **Specifications**

 $V_{\rm DD}$  = 2.7 V to 3.6 V, GND = 0 V, unless otherwise noted.

### Table 1.

Parameter	+25°C	-40°C to +85°C	Unit	Test Conditions/Comments
ANALOG SWITCH				
Analog Signal Range		0 V to V <sub>DD</sub>	V	
On-Resistance (R <sub>ON</sub> )	6.7		Ωtyp	$V_{DD} = 2.7 V$ , $V_{S} = 0 V$ to $V_{DD}$ , $I_{DS} = 10 m$ A; see Figure 21
		8.8	Ωmax	
On-Resistance Match	0.04		Ωtyp	$V_{DD} = 2.7 V$ , $V_{S} = 1.5 V$ , $I_{DS} = 10 mA$
Between Channels (ΔR <sub>ON</sub> )		0.2	Ωmax	
On Resistance Flatness (R <sub>FLAT (ON)</sub> )	3.3		Ωtyp	$V_{DD} = 2.7 V$ , $V_S = 0 V$ to $V_{DD}$ , $I_{DS} = 10 mA$
		3.6	Ωmax	
LEAKAGE CURRENTS				V <sub>DD</sub> = 3.6 V
Source Off Leakage Is (Off)	±0.2		nA typ	$V_{s} = 0.6 V/3.3 V$ , $V_{D} = 3.3 V/0.6 V$ ; see Figure 22
Channel On Leakage I <sub>D</sub> , Is (On)	±0.2		nA typ	$V_s = V_D = 0.6 V$ or 3.3 V; see Figure 23
DIGITAL INPUTS				
Input High Voltage, VINH		1.35	V min	
Input Low Voltage, VINL		0.8	V max	
Input Current, IINL or IINH	0.005		μA typ	$V_{IN} = V_{INL} \text{ or } V_{INH}$
		±0.1	μA max	$V_{IN} = V_{INL} \text{ or } V_{INH}$
Digital Input Capacitance, C <sub>IN</sub>	2		pF typ	
DYNAMIC CHARACTERISTICS <sup>1</sup>				
t <sub>on</sub>	9		ns typ	$R_L = 50 \Omega$ , $C_L = 35 pF$
	12.5	13.5	ns max	Vs = 2 V; see Figure 24
t <sub>OFF</sub>	6		ns typ	$R_L = 50 \Omega$ , $C_L = 35 pF$
	9.5	10	ns max	Vs = 2 V; see Figure 24
Propagation Delay	250		ps typ	$R_L = 50 \Omega$ , $C_L = 35 pF$
Propagation Delay Skew, t <sub>skew</sub>	20		ps typ	$R_L = 50 \Omega$ , $C_L = 35 pF$
Break-Before-Make Time Delay ( $t_{\text{BBM}}$ )	5		ns typ	$R_L = 50 \Omega$ , $C_L = 35 pF$
	3.4	2.9	ns min	$V_{S1} = V_{S2} = 2 V$ ; see Figure 25
Charge Injection	0.5		pC typ	$V_D = 1.25 V$ , $R_s = 0 \Omega$ , $C_L = 1 nF$ ; see Figure 26
Off Isolation	73		dB typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$ ; see Figure 27
Channel-to-Channel Crosstalk	-90		dB typ	S1A to S2A/S1B to S2B; $R_L = 50 \Omega$ , $C_L = 5 pF$ , f = 1 MHz; see Figure 28
	-80		dB typ	S1A to S1B/S2A to S2B; $R_L = 50 \Omega$ , $C_L = 5 pF$ , f = 1 MHz; see Figure 29
–3 dB Bandwidth	630		MHz typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ ; see Figure 30
Data Rate	1260		Mbps typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ ; see Figure 30
C <sub>s</sub> (Off)	2.4		pF typ	
C <sub>D</sub> , C <sub>s</sub> (On)	6.9		pF typ	
POWER REQUIREMENTS		1		V <sub>DD</sub> = 3.6 V
I <sub>DD</sub>	0.006		μA typ	Digital inputs = 0 V or 3.6 V
		1	µA max	

<sup>1</sup> Guaranteed by design, not subject to production test.

## **ABSOLUTE MAXIMUM RATINGS**

 $T_A = 25^{\circ}C$ , unless otherwise noted.

#### Table 2.

Parameter	Rating			
V <sub>DD</sub> to GND	-0.3 V to +4.6 V			
Analog Inputs, <sup>1</sup> Digital Inputs	–0.3 V to V <sub>DD</sub> + 0.3 V or 10 mA, whichever occurs first			
Peak Current, Pin S1A, Pin S2A, Pin D1, or Pin D2	100 mA (pulsed at 1 ms, 10% duty cycle max)			
Continuous Current, Pin S1A, Pin S2A, Pin D1, or Pin D2	30 mA			
Operating Temperature Industrial Range (B Version)	–40°C to +85°C			
Storage Temperature Range	–65°C to +150°C			
Junction Temperature	150°C			
θ <sub>JA</sub> Thermal Impedance (4-Layer Board)				
10-Lead Mini LFCSP	131.6°C/W			
12-Lead LFCSP	61°C/W			
Pb-Free Temperature, Soldering, IR Reflow				
Peak Temperature	260(+0/-5)°C			
Time at Peak Temperature	10 sec to 40 sec			

<sup>1</sup> Overvoltages at the IN1, IN2, S1A, S2A, D1, or D2 pin are clamped by internal diodes. Current must be limited to the maximum ratings given.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

Only one absolute maximum rating can be applied at any one time.

### **ESD CAUTION**



**ESD** (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

## **PIN CONFIGURATION AND FUNCTION DESCRIPTIONS**

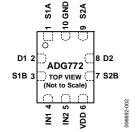
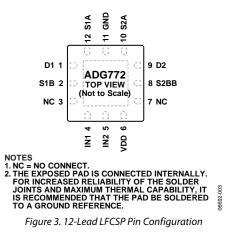


Figure 2. 10-Lead Mini LFCSP Pin Configuration



#### **Table 3. Pin Function Descriptions**

Pin No.					
10-Lead Mini LFCSP 12-Lead LFCSP		Mnemonic	Description		
1	12	S1A	Source Terminal. Can be an input or an output.		
2	1	D1	Drain Terminal. Can be an input or an output.		
3	2	S1B	Source Terminal. Can be an input or an output.		
4	4	IN1	Logic Control Input. This pin controls Switch S1A and Switch S1B to D1.		
5	5	IN2	Login Control Input. This pin controls Switch S2A and Switch S2B to D2.		
6	6	VDD	Most Positive Power Supply Potential.		
7	8	S2B	Source Terminal. Can be an input or an output.		
8	9	D2	Drain Terminal. Can be an input or an output.		
9	10	S2A	Source Terminal. Can be an input or an output.		
10	11	GND	Ground (0 V) Reference.		
Not applicable	3, 7	NC	No Connect.		
Not applicable	13	EPAD	Exposed Pad. The exposed pad is connected internally. For increased reliability of the solder joints and maximum thermal capability, it is recommended that the pad be soldered to a ground reference.		

### **TRUTH TABLE**

Table 4.

Logic (IN1 or IN2)	Switch A (S1A or S2A)	Switch B (S1B or S2B)
0	Off	On
1	On	Off

## **TYPICAL PERFORMANCE CHARACTERISTICS**

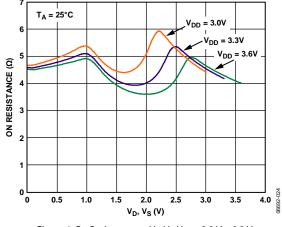


Figure 4. On Resistance vs.  $V_{Dr}$ ,  $V_{S}$ ;  $V_{DD}$  = 3.3 V ± 0.3 V

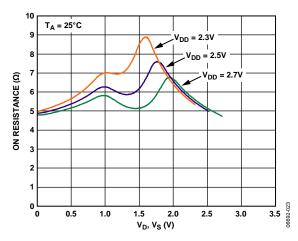


Figure 5. On Resistance vs.  $V_D$ ,  $V_S$ ;  $V_{DD} = 2.5 V \pm 0.2 V$ 

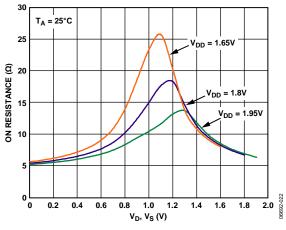


Figure 6. On Resistance vs.  $V_D$ ,  $V_S$ ;  $V_{DD} = 1.8 V \pm 0.15 V$ 

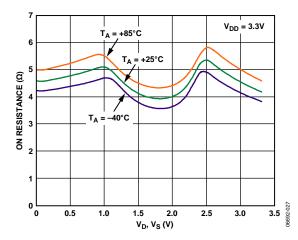


Figure 7. On Resistance vs.  $V_D$ ,  $V_S$  for Different Temperatures;  $V_{DD} = 3.3 V$ 

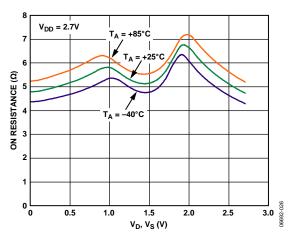


Figure 8. On Resistance vs.  $V_D$ ,  $V_S$  for Different Temperatures;  $V_{DD} = 2.7 V$ 

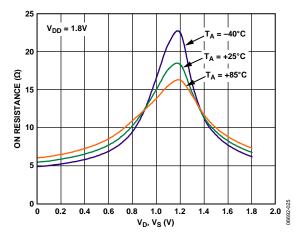


Figure 9. On Resistance vs.  $V_D$ ,  $V_S$  for Different Temperatures;  $V_{DD} = 1.8 V$ 

## Data Sheet

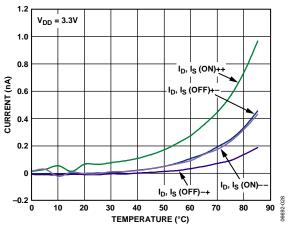


Figure 10. Leakage Current vs. Temperature; V<sub>DD</sub> = 3.3 V

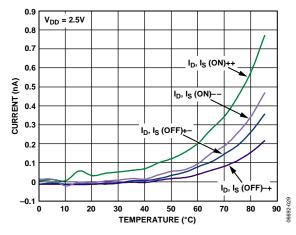


Figure 11. Leakage Current vs. Temperature;  $V_{DD} = 2.5 V$ 

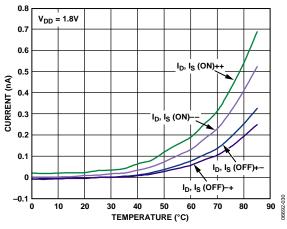


Figure 12. Leakage Current vs. Temperature; V<sub>DD</sub> = 1.8 V

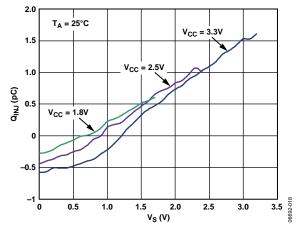
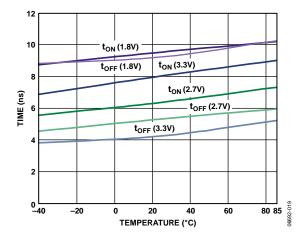
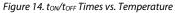
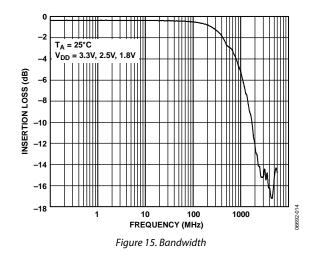


Figure 13. Charge Injection vs. Source Voltage







## ADG772

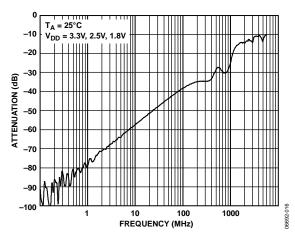
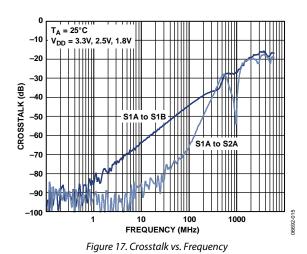
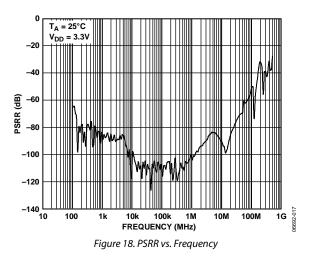


Figure 16. Off Isolation vs. Frequency





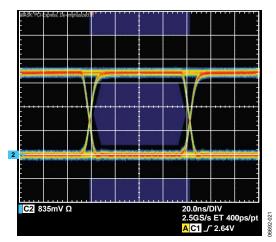


Figure 19. USB 1.1 Eye Diagram

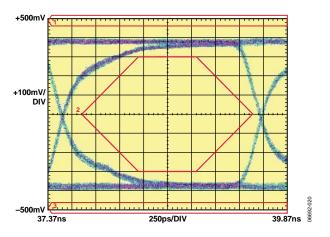
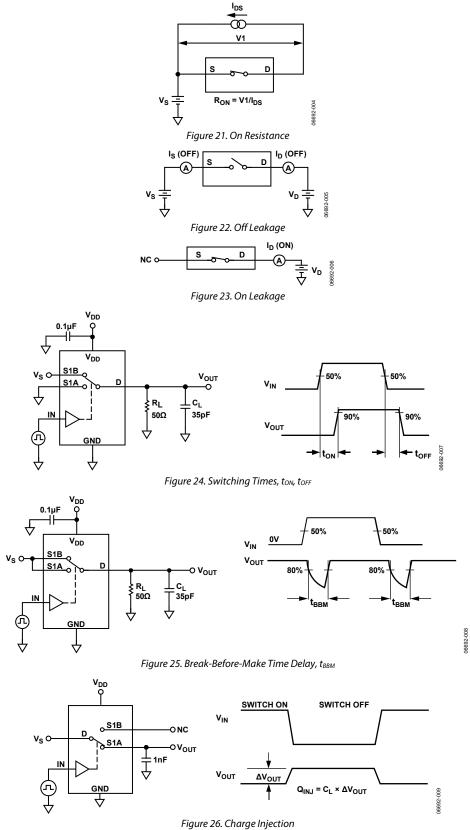
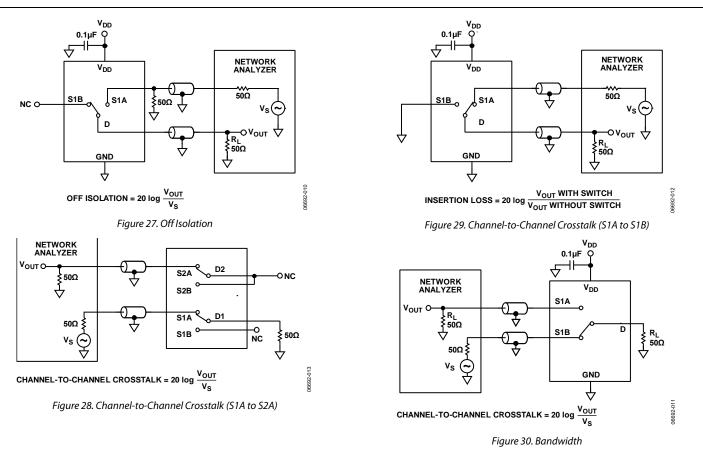


Figure 20. USB 2.0 Eye Diagram

## **TEST CIRCUITS**



## ADG772



## TERMINOLOGY

 $I_{\text{DD}}$ 

Positive supply current.

V<sub>D</sub>,V<sub>s</sub> Analog voltage on Terminal D and Terminal S.

**R**<sub>ON</sub> Ohmic resistance between Terminal D and Terminal S.

**R**<sub>FLAT</sub> (**On**) The difference between the maximum and minimum values of on resistance as measured on the switch.

 $\label{eq:dron} \Delta R_{\text{ON}}$  On resistance match between any two channels.

Is (Off) Source leakage current with the switch off.

I<sub>D</sub> (Off) Drain leakage current with the switch off.

I<sub>D</sub>, I<sub>S</sub> (On) Channel leakage current with the switch on.

V<sub>INL</sub> Maximum input voltage for Logic 0.

 $\mathbf{V}_{\text{INH}}$ Minimum input voltage for Logic 1.

 $I_{INL}, I_{INH}$  Input current of the digital input.

C<sub>s</sub> (Off) Off switch source capacitance. Measured with reference to ground.

 $C_D$  (Off) Off switch drain capacitance. Measured with reference to ground.

C<sub>D</sub>, C<sub>s</sub> (On) On switch capacitance. Measured with reference to ground.  $C_{IN}$ 

Digital input capacitance.

ton

Delay time between the 50% and 90% points of the digital input and switch on condition.

 $t_{\rm OFF}$  Delay time between the 50% and 90% points of the digital input and switch off condition.

**t**<sub>BBM</sub> On or off time measured between the 80% points of both switches when switching from one to another.

**Charge Injection** Measure of the glitch impulse transferred from the digital input to the analog output during on/off switching.

**Off Isolation** Measure of unwanted signal coupling through an off switch.

**Crosstalk** Measure of unwanted signal that is coupled from one channel to another as a result of parasitic capacitance.

**–3 dB Bandwidth** Frequency at which the output is attenuated by 3 dB.

**On Response** Frequency response of the on switch.

**Insertion Loss** The loss due to the on resistance of the switch.

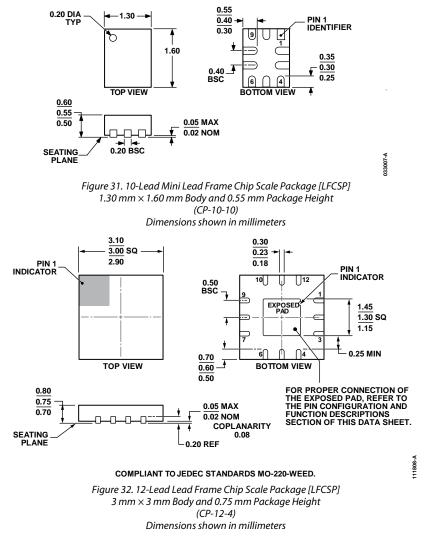
**THD + N** Ratio of the harmonics amplitude plus noise of a signal to the fundamental.

T<sub>skew</sub>

The measure of the variation in propagation delay between each channel.

## ADG772

## **OUTLINE DIMENSIONS**



### **ORDERING GUIDE**

Model <sup>1</sup>	Temperature Range	Package Description	Package Option	Branding
ADG772BCPZ-1REEL	-40°C to +85°C	12-Lead Lead Frame Chip Scale Package [LFCSP]	CP-12-4	S2P
ADG772BCPZ-REEL7	-40°C to +85°C	10-Lead Mini Lead Frame Chip Scale Package [LFCSP]	CP-10-10	В
EVAL-ADG772EBZ	-40°C to +85°C	Evaluation Board		

<sup>1</sup> Z = RoHS Compliant Part.

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